Complementary Silicon Plastic Power Transistors

These devices are designed for use as high-frequency drivers in audio amplifiers.

Features

- High Current Gain Bandwidth Product
- TO-220 Compact Package
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|---|-----------------------------------|--------------|-----------|
| Collector–Emitter Voltage MJE15028G, MJE15029G MJE15030G, MJE15031G | V _{CEO} | 120 150 | Vdc |
| Collector-Base Voltage MJE15028G, MJE15029G MJE15030G, MJE15031G | V _{CB} | 120 150 | Vdc |
| Emitter-Base Voltage | V _{EB} | 5.0 | Vdc |
| Collector Current – Continuous | I _C | 8.0 | Adc |
| Collector Current – Peak | I _{CM} | 16 | Adc |
| Base Current | Ι _Β | 2.0 | Adc |
| Total Device Dissipation @ T _C = 25°C Derate above 25°C | P _D | 50 0.40 | W W/°C |
| Total Device Dissipation @ T _A = 25°C Derate above 25°C | P _D | 2.0 0.016 | W W/°C |
| Operating and Storage Junction Temperature Range | T _J , T _{stg} | -65 to +150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

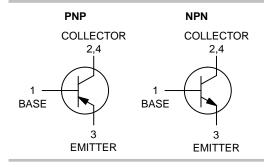
| Characteristics | Symbol | Max | Unit |
|---|-----------------|------|------|
| Thermal Resistance, Junction-to-Case | $R_{\theta JC}$ | 2.5 | °C/W |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 62.5 | °C/W |

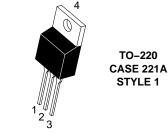


ON Semiconductor®

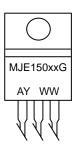
http://onsemi.com

8 AMPERE POWER TRANSISTORS COMPLEMENTARY SILICON 120-150 VOLTS, 50 WATTS





MARKING DIAGRAM



MJE150xx = Device Code x = 28, 29, 30, or 31

= Assembly Location

Y = Year WW = Work Week G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit |
|---|-----------------------|----------------------|------------------|------|
| OFF CHARACTERISTICS | <u>.</u> | | | |
| Collector–Emitter Sustaining Voltage (Note 1) ($I_C = 10 \text{ mAdc}$, $I_B = 0$) MJE15028, MJE15029 MJE15030, MJE15031 | V _{CEO(sus)} | 120 150 | - - | Vdc |
| Collector Cutoff Current $(V_{CE} = 120 \text{ Vdc}, I_B = 0)$ MJE15028, MJE15029 $(V_{CE} = 150 \text{ Vdc}, I_B = 0)$ MJE15030, MJE15031 | I _{CEO} | - | 0.1 0.1 | mAdc |
| Collector Cutoff Current $(V_{CB} = 120 \text{ Vdc}, I_E = 0)$ MJE15028, MJE15029 $(V_{CB} = 150 \text{ Vdc}, I_E = 0)$ MJE15030, MJE15031 | I _{CBO} | - | 10 10 | μAdc |
| Emitter Cutoff Current (V _{BE} = 5.0 Vdc, I _C = 0) | I _{EBO} | - | 10 | μAdc |
| ON CHARACTERISTICS (Note 1) | | | | |
| DC Current Gain ($I_C = 0.1 \text{ Adc}, V_{CE} = 2.0 \text{ Vdc}$) ($I_C = 2.0 \text{ Adc}, V_{CE} = 2.0 \text{ Vdc}$) ($I_C = 3.0 \text{ Adc}, V_{CE} = 2.0 \text{ Vdc}$) ($I_C = 4.0 \text{ Adc}, V_{CE} = 2.0 \text{ Vdc}$) | h _{FE} | 40 40 40 20 | - - - - | _ |
| DC Current Gain Linearity (V _{CE} From 2.0 V to 20 V, I _C From 0.1 A to 3 A) (NPN to PNP) | h _{FE} | Typ 2 3 | | |
| Collector–Emitter Saturation Voltage (I _C = 1.0 Adc, I _B = 0.1 Adc) | V _{CE(sat)} | - | 0.5 | Vdc |
| Base–Emitter On Voltage (I _C = 1.0 Adc, V _{CE} = 2.0 Vdc) | V _{BE(on)} | - | 1.0 | Vdc |
| DYNAMIC CHARACTERISTICS | <u> </u> | | | |
| Current Gain – Bandwidth Product (Note 2) $(I_C = 500 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f_{test} = 10 \text{ MHz})$ | f⊤ | 30 | - | MHz |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 1. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

^{2.} $f_T = |h_{fe}| \cdot f_{test}$.

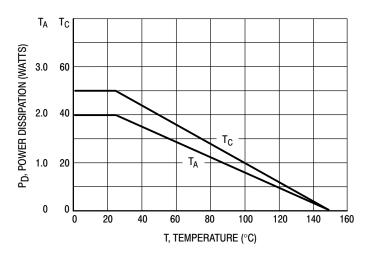


Figure 1. Power Derating

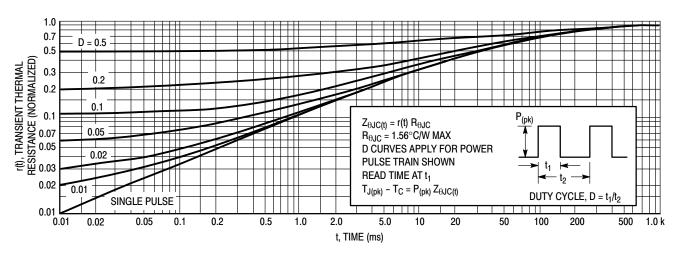


Figure 2. Thermal Response

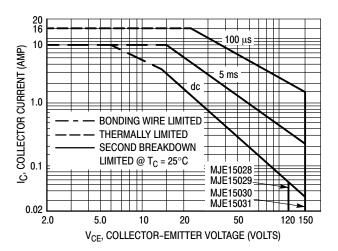


Figure 3. Forward Bias Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation, i.e., the transistor must not be subjected to greater dissipation then the curves indicate.

The data of Figures 3 and 4 is based on $T_{J(pk)}=150^{\circ}C$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)}$ < 150°C. $T_{J(pk)}$ may be calculated from the data in Figure 2. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

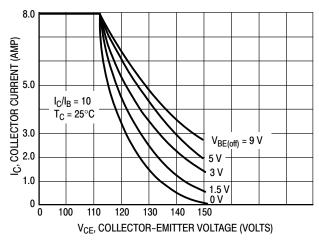


Figure 4. Reverse-Bias Switching Safe Operating Area

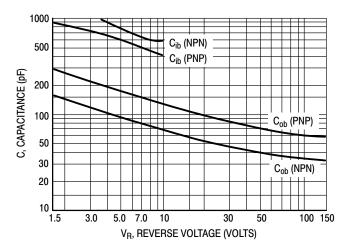
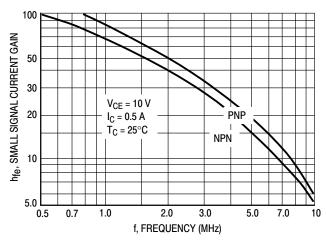


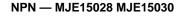
Figure 5. Capacitances

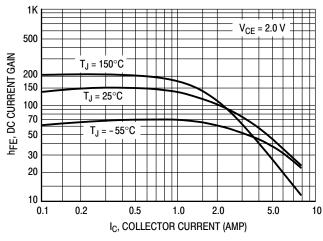


100 f_T, CURRENT GAIN-BANDWIDTH PRODUCT (MHz) 90 (PNP) (NPN) 60 20 10 0 L 0.1 0.2 0.5 2.0 5.0 1.0 10 IC, COLLECTOR CURRENT (AMP)

Figure 6. Small-Signal Current Gain

Figure 7. Current Gain-Bandwidth Product





PNP — MJE15029 MJE15031

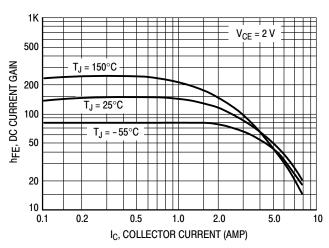
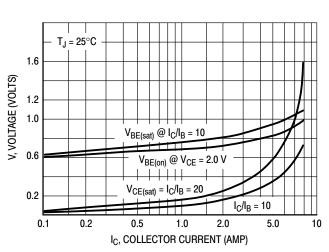
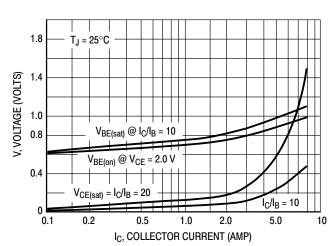


Figure 8. DC Current Gain



NPN



PNP

Figure 9. "On" Voltage

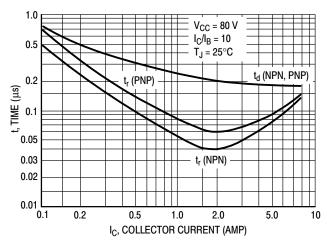


Figure 10. Turn-On Times

Figure 11. Turn-Off Times

ORDERING INFORMATION

| Device | Package | Shipping |
|-----------|---------------------|-----------------|
| MJE15028G | TO-220 (Pb-Free) | 50 Units / Rail |
| MJE15029G | TO-220 (Pb-Free) | 50 Units / Rail |
| MJE15030G | TO-220 (Pb-Free) | 50 Units / Rail |
| MJE15031G | TO-220 (Pb-Free) | 50 Units / Rail |

onsemi, Onsemi, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA class 3 medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales